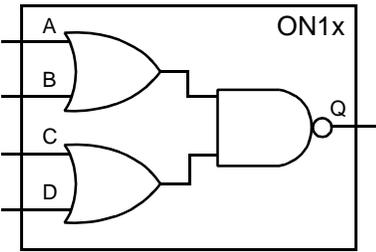


AMI5HG 0.5 micron CMOS Gate Array

Description

ON1x is a family of OR-NAND circuits consisting of two 2-input OR gates into a 2-input NAND gate.

Logic Symbol	Truth Table																				
	<table border="1"> <thead> <tr> <th>A</th> <th>B</th> <th>C</th> <th>D</th> <th>Q</th> </tr> </thead> <tbody> <tr> <td>L</td> <td>L</td> <td>X</td> <td>X</td> <td>H</td> </tr> <tr> <td>X</td> <td>X</td> <td>L</td> <td>L</td> <td>H</td> </tr> <tr> <td colspan="4">All other combinations</td> <td>L</td> </tr> </tbody> </table>	A	B	C	D	Q	L	L	X	X	H	X	X	L	L	H	All other combinations				L
A	B	C	D	Q																	
L	L	X	X	H																	
X	X	L	L	H																	
All other combinations				L																	

Core Logic

HDL Syntax

Verilog ON1x *inst_name* (Q, A, B, C, D);

VHDL *inst_name*: ON1x port map (Q, A, B, C, D);

Pin Loading

Pin Name	Equivalent Loads			
	ON11	ON12	ON14	ON16
A	1.0	1.0	1.0	2.1
B	1.0	1.0	1.0	2.1
C	1.0	1.0	1.0	2.1
D	1.0	1.0	1.0	2.1

Size And Power Characteristics

Cell	Equivalent Gates	Power Characteristics ^a	
		Static I _{DD} (T _J = 85°C) (nA)	EQL _{pd} (Eq-load)
ON11	2.0	TBD	2.3
ON12	4.0	TBD	6.6
ON14	4.0	TBD	7.6
ON16	8.0	TBD	15.7

a. See page 2-15 for power equation.

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Propagation Delays (ns)

Conditions: $T_J = 25^\circ\text{C}$, $V_{DD} = 5.0\text{V}$, Typical Process

ON11	Number of Equivalent Loads		1	2	5	8	10 (max)
	From: Any Input To: Q	t_{PLH} t_{PHL}	0.16 0.21	0.22 0.26	0.39 0.41	0.54 0.54	0.64 0.63
ON12	Number of Equivalent Loads		1	4	8	13	17 (max)
	From: Any Input To: Q	t_{PLH} t_{PHL}	0.37 0.38	0.47 0.50	0.59 0.64	0.73 0.79	0.84 0.91
ON14	Number of Equivalent Loads		1	8	15	22	30 (max)
	From: Any Input To: Q	t_{PLH} t_{PHL}	0.39 0.42	0.50 0.59	0.59 0.71	0.69 0.82	0.81 0.93
ON16	Number of Equivalent Loads		1	14	28	42	56 (max)
	From: Any Input To: Q	t_{PLH} t_{PHL}	0.37 0.42	0.46 0.57	0.54 0.70	0.63 0.81	0.73 0.91

Delay will vary with input conditions. See page 2-17 for interconnect estimates.